NSN 5961-00-004-2018

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.170 inches
Terminal Length:
1.000 inches
Overall Diameter:
0.076 inches
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-70.0 breakdown voltage, dc
Current Rating Per Characteristic:
15.00 microamperes reverse current, dc
Power Rating Per Characteristic:
250.0 milliwatts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0